

Room-temperature coexistence of large electric polarization and magnetic order in BiFeO₃ single crystals

D. Lebeugle,¹ D. Colson,¹ A. Forget,¹ M. Viret,¹ P. Bonville,¹ J. F. Marucco,^{1,2} and S. Fusil³

¹*Service de Physique de l'Etat Condensé, DSM/DRECAM, CEA Saclay, 91191 Gif-Sur-Yvette Cedex, France*

²*Laboratoire d'Etude des Matériaux Hors-Equilibre, Université Paris-Sud, Bât. 415, 91405 Orsay Cedex, France*

³*Unité mixte de Physique, CNRS-Thalès URA 2464, Route Départementale 128, 91767 Palaiseau, France*

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From an experimental point of view, room-temperature ferroelectricity in BiFeO₃ is raising many questions. Electric measurements made a long time ago on solid solutions of BiFeO₃ with Pb(Ti,Zr)O₃ indicate that a spontaneous electric polarization exists in BiFeO₃ below the Curie temperature $T_C=1143$ K. Yet in most reported works, the synthesized samples are too conductive at room temperature to get a clear polarization loop in the bulk without any effects of extrinsic physical or chemical parameters. Surprisingly, up to now there has been no report of a $P(E)$ (polarization versus electric field) loop at room temperature on single crystals of BiFeO₃. We describe here our procedure to synthesize ceramics and to grow good quality sizeable single crystals by a flux method. We demonstrate that BiFeO₃ is indeed ferroelectric at room temperature through evidence by piezoresponse force microscopy and $P(E)$ loops. The polarization is found to be large, around $60 \mu\text{C}/\text{cm}^2$, a value that has only been reached in thin films. Magnetic measurements using a superconducting quantum interference device magnetometer and Mössbauer spectroscopy are also presented. The latter confirms the results of nuclear magnetic resonance measurements concerning the anisotropy of the hyperfine field attributed to the magnetic cycloidal structure.

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I. INTRODUCTION

Recently, the perovskite-type oxides, which display ferroelectric and magnetic properties, have been the object of a renewed interest as a significant interplay between the two orders would open potential applications in spintronic devices.¹ It has been shown that BiFeO₃ is a good candidate as the space group $R3c$ allows the existence of both antiferromagnetic and ferroelectric orders with very high transition temperatures. BiFeO₃ is antiferromagnetic below the Néel temperature $T_N=643$ K (neutron powder diffraction²) with a long-range cycloidal spiral incommensurate with the lattice;³ it is also ferroelectric below $T_C=1143$ K (dielectric measurements⁴ and x-ray single crystal diffraction²).

Numerous studies have been performed on BiFeO₃ samples and especially, more recently, on thin films.⁵⁻⁸ A significant enhancement of the polarization in thin films has been reported in comparison with the bulk and recently, electrical control of antiferromagnetic domains in BiFeO₃ films at room temperature has even been evidenced.^{5,6} However it was also argued that epitaxial strain does not enhance the magnetization and polarization in BiFeO₃ and that increased thickness-dependent magnetization is not an intrinsic property of fully oxygenated and coherently strained epitaxial BiFeO₃ films which exhibit a high electrical resistivity.⁹ Furthermore, the conduction in most BiFeO₃ ceramics or films seems to be extrinsic, limited by oxygen vacancies, and it is easily rectified by replacing some Fe with Mn.¹⁰ Recently, the large spontaneous polarization measured in thin films has been confirmed at room temperature by local piezoresponse hysteresis curve in ceramic BiFeO₃ (Ref. 11) and also by means of polarization loop measurements on high resistive single crystals.¹²

Concerning the coupling between magnetic and electric orders in the bulk, a quadratic magnetoelectric signal has

been observed at 4 K.¹³ The main limitation for electric measurements is the leakage current which generally prevents the application of a reasonably high electric field on the sample. Hence, very pure samples are required since secondary phases and grain boundaries are responsible for the leakage currents. We present here our improvements to the synthesis of BiFeO₃ ceramic and single crystals. The high quality achieved in the single crystals allowed us to measure a polarization loop at room temperature. The ferroelectric behavior of BiFeO₃ is also evidenced by piezoelectric force microscopy measurements. We also demonstrate the absence of weak ferromagnetism in bulk BiFeO₃ single crystals, and we present a brief discussion of the effect of a spiral magnetic structure on the ⁵⁷Fe Mössbauer absorption spectra, and a comparison with nuclear magnetic resonance (NMR) measurements.¹⁴

II. SAMPLE PREPARATION

The synthesis of pure polycrystalline BiFeO₃ samples is quite subtle because it is necessary to take both kinetic and thermodynamic properties into account. As can be seen in the phase diagram,¹⁵ two impurities can be formed along with BiFeO₃. Indeed the high volatility of Bi₂O₃ leads to the formation of a Bi-poor phase Bi₂Fe₄O₉, but a small excess of Bi₂O₃ in the reactants, necessary to compensate for the loss of Bi₂O₃, leads to the formation of a Bi-rich phase Bi₂₅FeO₃₉. Differential thermal analysis and kinetic investigations^{16,17} show that the reaction in equimolar mixture of BiFeO₃ is complex. Below 675 °C the reaction is incomplete. From 675 °C to 830 °C, BiFeO₃ decomposes very slowly into Bi₂Fe₄O₉, whereas above 830 °C BiFeO₃ separates rapidly into Bi₂Fe₄O₉. A previous reported synthesis of BiFeO₃ using solid state reactions¹⁸ needs a very large

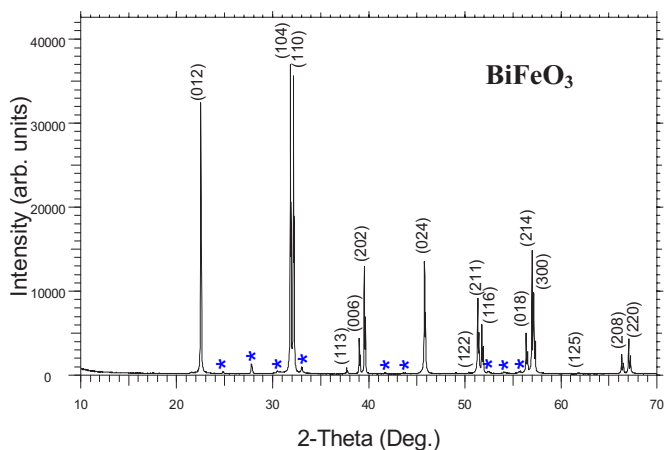


FIG. 1. (Color online) Powder x-ray diffraction pattern of BiFeO_3 at 300 K using $\text{Cu}_{K\alpha}$ radiation. The asterisks correspond to the $\text{Bi}_{25}\text{FeO}_{39}$ impurity. BiFeO_3 is present as the major phase.

excess of Bi_2O_3 (100%) to prevent the formation of $\text{Bi}_2\text{Fe}_4\text{O}_9$, but the disadvantage of this technique is to form a large quantity of $\text{Bi}_{25}\text{FeO}_{39}$ that cannot be separated from BiFeO_3 with a good yield.

We propose here to use the solid state reaction from a stoichiometric mixture by adjusting temperature and time in order to get a complete reaction while preventing the formation of both impurities. This way of preparation differs from the rapid sintering technique previously developed^{19,20} at higher temperatures which can lead to a sample contamination by the crucible. The details of our preparation are as follows: a stoichiometric $\text{Bi}_2\text{O}_3:\text{Fe}_2\text{O}_3$ mixture is ground finely and sintered in air for 15 h at 800 °C using an alumina crucible. It should be noted that the crucible can only be used for one or two experiments; after this the porosity of the crucible may cause a loss of Bi. Powder x-ray diffraction data were collected at room temperature using a “D8 Advance” diffractometer (Bruker-axs) with $\text{Cu}_{K\alpha}$ radiation ($\lambda = 1.5418 \text{ \AA}$) and a scan rate of 0.02° per 20 s. Intensities of 18 reflections in the range $10^\circ < 2\theta < 70^\circ$ were collected with an energy dispersive detector (“Sol-X” Bruker). The analysis shows no traces of $\text{Bi}_2\text{Fe}_4\text{O}_9$ but a small amount of $\text{Bi}_{25}\text{FeO}_{39}$ (Fig. 1). This parasitic phase can be leached in 10% diluted HNO_3 . With this technique, we obtain a dark-brown single-phase polycrystalline BiFeO_3 which has been used to grow epitaxial thin films.²¹

The possible nonstoichiometry of $\text{BiFeO}_{3+\delta}$ was studied by thermogravimetry in a controlled atmosphere between 25 °C and 800 °C. The experimental setup has been previously described.²² It consists of a Setaram B60 thermobalance with a working sensibility of 0.015 mg corresponding to $\Delta\delta = 5 \times 10^{-4}$ for a mass sample of 1.5 g. A Chevenard furnace was used to adjust the temperature. The BiFeO_3 powder was directly heated in a recrystallized alumina crucible under pure oxygen and then argon atmospheres. The oxygen pressure in argon corresponds to 10^{-5} atm. No composition variation was detected in the studied temperature range both under oxygen and argon, characterizing a stoichiometric compound. The use of more reducing atmospheres (CO-CO_2 or $\text{H}_2\text{-H}_2\text{O}$), corresponding thermo-

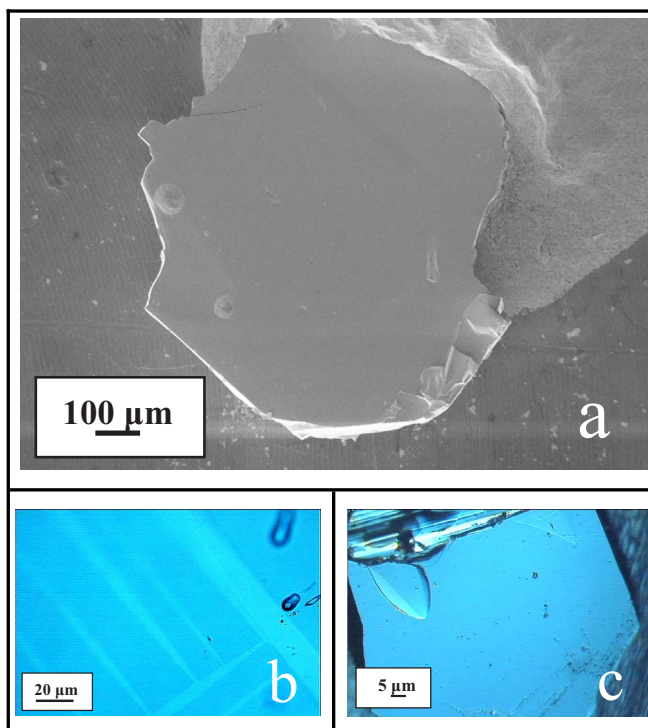


FIG. 2. (Color online) (a) SEM image of a BiFeO_3 single crystal platelet grown by slow cooling from a $\text{Bi}_2\text{O}_3/\text{Fe}_2\text{O}_3$ flux. The crystal size is about $1.4 \times 1.6 \times 0.04 \text{ mm}^3$. (b) A photograph of one part of a BiFeO_3 single crystal examined under a polarizing microscope with a polychromatic light. The contrast between bright and dark regions is due to positive and negative orientations of the spontaneous polarization. (c) A photograph of another BiFeO_3 single crystal examined under a polarizing microscope with a polychromatic light. Only one single ferroelectric domain is visible.

dynamically to Fe^{2+} or Bi metal, would lead to the decomposition of the perovskite phase.

In order to study the intrinsic properties of BiFeO_3 , we have also developed a procedure to grow single crystals of a millimetric size needed for physical measurements. More specifically, electrical measurements require producing platelets with one reduced dimension and two large ones, hence maximizing the electric field which can be applied on the material as well as optimizing the charges on both sides (which are proportional to the sample area). The single crystals were grown in air from a $\text{Bi}_2\text{O}_3\text{-Fe}_2\text{O}_3$ flux with a mole ratio 3.5:1 using an alumina crucible. A fine and homogeneous mixture was obtained from approximately 75 g quantity of the highly pure oxides Bi_2O_3 and Fe_2O_3 stirred with deionized water using a grinding mill (Attritor). In order to increase the surface-to-volume ratio, we put a thin layer of the melt (2 cm) in an alumina crucible 6 cm in diameter. The mixture was heated up to 850 °C at a rate of 150 °C/h, held for 4 h at this temperature and was cooled down slowly to 750 °C; at this point the furnace was turned off. The crystals grown in this way are millimeter-sized black platelets [Fig. 2(a)]. They can be extracted from the solid flux mechanically. Electron microprobe analysis confirms the stoichiometry of BiFeO_3 .

The ferroelectric domains have been observed under a polarizing microscope in reflectivity mode [Fig. 2(b)]. The

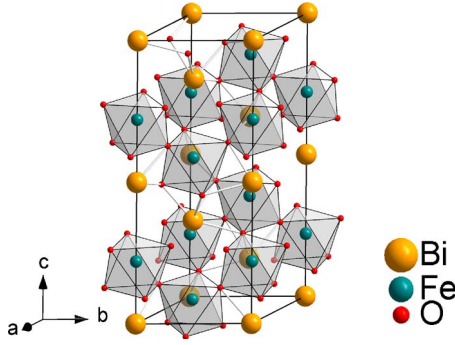


FIG. 3. (Color online) Drawing of the hexagonally distorted perovskite-type BiFeO_3 cell using Diamond 3.1 software. Oxygen octahedra are top connected and oppositely rotated around the threefold axis. All the atomic displacements responsible for the appearance of a dipolar moment occur along the threefold axis.

contrast between bright domains (which correspond to a direction of the spontaneous polarization) and dark domains (which corresponds to the opposite one) comes from the birefringence property of the ferroelectric crystal. Then we are able to select from the batch crystals of single ferroelectric domain type [Fig. 2(c)].

III. SINGLE CRYSTAL X-RAY ANALYSIS

Four-circle x-ray diffraction data were collected at room temperature on a single crystal by using a Kappa X8 APPEX II Bruker diffractometer with graphite-monochromated $\text{Mo}_{K\alpha}$ radiation ($\lambda=0.71073 \text{ \AA}$). Lattice parameters were determined from 1230 reflections in the range of $2.64^\circ < \theta < 32.2^\circ$ using a two-dimensional detector. The data were corrected for Lorentz polarization, and absorption effects. The structure was solved by direct methods using SHELXS-97 (Ref. 23) and refined against F^2 by full-matrix least-squares techniques using SHELXL-97 (Ref. 24) with anisotropic displacement parameters for all atoms. All calculations were performed by using the Crystal Structure Crystallographic software package WINGX.²⁵ The crystals have a rhombohedrally distorted perovskite-type cell with lattice constants $a_{\text{hex}}=5.571 \text{ \AA}$ and $c_{\text{hex}}=13.868 \text{ \AA}$ at room temperature. The space group is determined as $R3c$ with six formula units in the unit cell (Fig. 3). Data collection and refinement parameters are given in Table I. They are close to those obtained by Kubel and Schmid by x-ray diffraction ($a_{\text{hex}}=5.579 \text{ \AA}$, $c_{\text{hex}}=13.869 \text{ \AA}$).²⁶ This setup allows us to orient the crystal correctly for magnetic and electric measurements. The largest side of the crystal corresponds to the $(012)_{\text{hex}}$ plane [the $(010)_{\text{cub}}$ plane]. The axis perpendicular to this plane makes an angle of $54^\circ 44'$ with the c axis.

IV. FERROELECTRIC PROPERTIES

The ferroelectric character of polycrystalline samples at room temperature has already been evidenced by the observation of saturation polarization loops.^{19,20,27} However, contributions from leakage currents and the samples own capacitance makes it difficult to quantify the intrinsic polarization

TABLE I. Four-circle x-ray diffraction data at 300 K for a single crystal of BiFeO_3 using a $\text{Mo}_{K\alpha}$ radiation ($\lambda=0.71073 \text{ \AA}$).

Formula	BiFeO_3
FW (g mol^{-1})	312.825
Crystal system	Rhombohedral
Space group	$R3c$
a_{hex} (\AA)	5.571(5)
b_{hex} (\AA)	5.571(5)
c_{hex} (\AA)	13.858(5)
α ($^\circ$)	90
β ($^\circ$)	90
γ ($^\circ$)	120
V (\AA^3)	372.53(1)
Z	6
ρ (g cm^{-3})	8.33
Crystal size (mm^3)	$0.3 \times 0.2 \times 0.02$
$F(000)$	798
λ ($K\alpha$ Mo) (\AA)	0.71073
T (K)	293(2)
μ (mm^{-1})	76.32
θ range ($^\circ$ min max)	2.64–52.66
Number of data collected	12 952
Number of unique data	414
$R(\text{int})$	0.0676
Number of variable parameters	16
Number of observed reflections ^a	344
R^b observed	0.0763
R_w^c observed	0.2232
Goodness of fit S	1.115
$(\Delta/\sigma)_{\text{max}}$	0.091
$(\Delta/\rho)_{\text{min}}$ ($e \text{ \AA}^{-3}$)	-2.558
$(\Delta/\rho)_{\text{max}}$ ($e \text{ \AA}^{-3}$)	3.651

^aData with $F_o > 4\sigma(F_o)$.

^b $R = \sum ||F_o| - |F_c|| / \sum |F_o|$.

^c $R_w = [\sum w(|F_o|^2 - |F_c|^2)^2 / \sum w |F_o|^2]^{1/2}$.

of the ceramics. As a result, very low values of the polarization have generally been inferred from the $P(E)$ loops (about $6 \mu\text{m cm}^{-2}$). Indeed the conductivity of BiFeO_3 is not negligible at room temperature, presumably due to impurities at the grain boundaries that lead to high porosity. It should be noted that another way to obtain a higher dielectric constant and a lower dielectric loss factor is to make solid solutions of BiFeO_3 with another ABO_3 perovskite such as $\text{BiFeO}_3\text{-Pb(Ti,Zr)O}_3$.⁴ The measurements are made possible that way, but a proper quantification of the polarization and coercive fields is also difficult. It is easier to measure epitaxial thin film and much larger values (about $60 \mu\text{m cm}^{-2}$) have been reported.⁴ The general belief is that this tenfold enhancement of the remanent polarization in thin films is due to a structural modification (to a tetragonal crystal structure) coming from compressive stress imposed by the substrate. Here, we show that the large values found in films are intrinsic to BiFeO_3 phase as demonstrated by the room-

temperature polarization we measure in high-purity single crystals. These large values of polarization are actually consistent with theoretical predictions.²⁸ From piezoelectric force microscopy measurements, the remnant out-of-plane piezoelectric coefficient d_{33} in these films is about 70 pm/V.

In this paper, we report on our work on the pure bulk compounds. Our efforts to compact sintered samples by isostatic pressure (2500 bars) lead to an increase in resistivity, but this was still not sufficient to obtain a clear polarization loop at room temperature. To overcome these persistent problems, we have chosen to synthesize single crystals. Surprisingly, up to now only very few measurements have been reported on single crystals, including a minor hysteresis loop at 77 K.²⁹ The measured spontaneous polarization was $3.5 \mu\text{C cm}^{-2}$ along the $[100]_{\text{hex}}$ direction, which would represent $6.1 \mu\text{C cm}^{-2}$ in the $[111]_{\text{hex}}$ direction. According to the authors, the difficulty to obtain a well saturated $P(E)$ loop comes from the high conductivity of BiFeO_3 for temperatures above 190 K [$\rho(300 \text{ K}) \approx 0.2 - 1 \times 10^5 \Omega\text{m}$ at 1 kHz (Ref. 30)]. This is probably due to impurities on the surface or inclusions in the crystals. Clearly, there is a need for more measurements on pure crystals.

A. Piezoelectric force microscopy

The ferroelectric behavior of a $40 \mu\text{m}$ thick BiFeO_3 single crystal obtained by the previously described method was assessed at room temperature by piezoelectric force microscopy (PFM). The crystal was polished to a thin platelet to ensure that the bias range available in the PFM setup was sufficient to reverse the polarization. The BiFeO_3 platelet was fixed with silver paint acting as a bottom electrode while a bias is applied on the conductive atomic force microscope tip used as the top electrode. Imaging of the domains is carried out by applying a small ac bias on the bottom electrode (~ 10 times lower than the coercive voltage) giving rise to the converse piezoelectric effect detected through lock-in techniques. The out-of-plane phase component (OP-PFM) of the piezoresponse is homogeneous over areas as large as $20 \times 20 \mu\text{m}^2$ demonstrating that only four among the eight possible polarization variants may be present [Fig. 4(a)]. The in-plane phase component (IP-PFM) exhibits two levels of contrast shifted by 180° one from the other most likely because of sample roughness at a submicrometric scale [Fig. 4(b)].

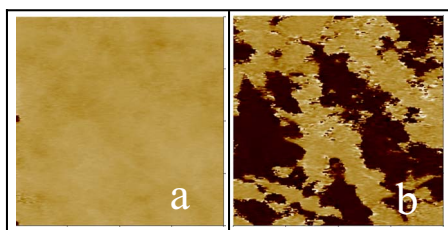


FIG. 4. (Color online) PFM images ($20 \times 20 \mu\text{m}^2$ area) of a BiFeO_3 polished single crystal. (a) Out-of-plane PFM phase homogeneous image. (b) In-plane PFM phase image: the two tones are shifted by 180° one from each other most likely because of sample roughness.

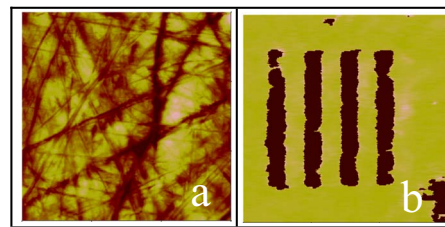


FIG. 5. (Color online) PFM images ($6 \times 6 \mu\text{m}^2$ area) of the thinnest region of a BiFeO_3 polished single crystal. (a) Topography. Polishing scratches are visible. (b) Out-of-plane PFM phase image after writing “up” and “down” stripes (size, $4 \times 0.5 \mu\text{m}$). The out-of-plane polarization induced by negative voltage has the same direction as the spontaneous one.

Figure 5(a) shows the topography of the thinnest region of the single crystal ($6 \times 6 \mu\text{m}^2$ area). By applying a dc bias to the scanning tip, it is possible to draw ferroelectric patterns: “up” and “down” stripes ($0.5 \times 4 \mu\text{m}^2$) were written with a positive and negative dc bias, respectively. The pattern written can be subsequently imaged as shown in Fig. 5(b) revealing the written stripes.

A local hysteretic cycle can be measured through the local piezoelectric response versus applied voltage. The typical cycle shown in Fig. 6 unambiguously confirms the ferroelectric nature of the single crystal at room temperature. A quantitative estimate of the piezoresponse and of the coercive field by this technique requires the elaboration of plane capacitors. In the experiments reported here, the effective electric field is amplified by the tip effect and hence not precisely known. Taking a rough estimate for the tip radius at its apex (around 100 nm), we can infer a coercive field of a few tens of kV/cm.

B. Charge current versus applied voltage

Larger crystals have been used for polarization loop measurements in a capacitor geometry by a standard macroscopic method which consists in measuring the current flowing in a simple resistive circuit as a function of the voltage applied to the sample [$I(V)$ characteristic]. Any change of the sample polarization induces a transfer of charges which is measured by a picoampere meter. This current is the time derivative of

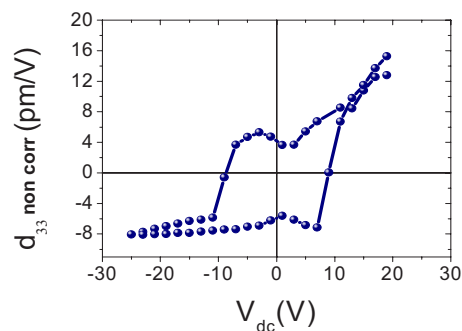


FIG. 6. (Color online) Local piezoelectric coefficient d_{33} (not corrected by the tip effect) versus applied high voltage hysteresis at room temperature on a single crystal of BiFeO_3 .

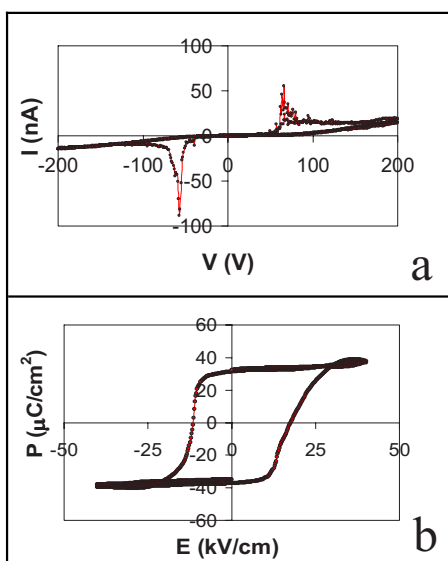


FIG. 7. (Color online) (a) Charge current versus applied voltage of a $40 \mu\text{m}$ thick single crystal of BiFeO_3 at room temperature. The raw data are composed of a background leakage current superimposed to the relevant signal. (b) P - E hysteresis loop of the $40 \mu\text{m}$ thick single crystal of BiFeO_3 at room temperature.

the charge, which is directly related to the polarization cycle. Experimentally, one measures a small leakage current (due to the fact that the sample has a finite resistance) superimposed to the derivative of the ferroelectric hysteresis cycle. For the measurements presented here, electrodes were apposed using silver paste applied on the two major faces of the sample [which correspond to the plane $(012)_{\text{hex}}$] and copper wires were used to apply the voltage across the crystal. The electric field dependence of the charge current (I - E) was measured using a Keithley picoamperemeter and voltage source. The maximum electric field that could be applied on our samples is 125 kV/cm , which proved high enough to observe a hysteresis cycle. As shown in Fig. 7(a), the raw data are composed of a background leakage current superimposed to the relevant signal composed of two peaks, either positive or negative, which are due to the charges flowing through the circuit when the sample polarization reverses. The resistance of the sample is very high [$\rho(300 \text{ K}, 100 \text{ V}) \sim 6 \times 10^{10} \Omega \text{ cm}$] hence allowing us to observe a large polarization loop. In order to precisely extract the charge current from the measured leakage current, we fitted the latter to a V^3 dependence typical from leakage current. When integrating the signal, a hysteresis cycle can be reconstructed as shown in Fig. 7(b). The relevant quantities of spontaneous polarization and coercive fields, in the direction of the applied electric field, can be easily and reliably extracted. We found for our BiFeO_3 single crystal at room temperature a remnant polarization $P_{(012)}$ of $35 \mu\text{C cm}^{-2}$ and a coercivity of 15 kV/cm . Taking into account that our measurement is not in the exact easy direction (but canted by $54^\circ 44'$), the inferred full saturation polarization along the $[001]$ direction is close to $60 \mu\text{C cm}^{-2}$. This value is in good agreement with theoretical predictions²⁸ and thin film data,⁵ but it contradicts previous room-temperature measurements in bulk systems

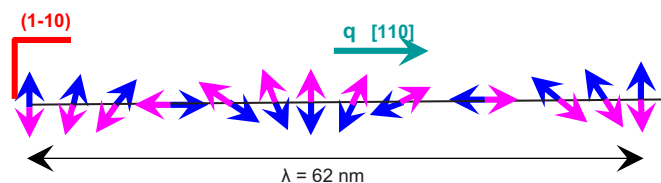


FIG. 8. (Color online) Schematic antiferromagnetic structure of BiFeO_3 where the two AF sublattices are organized along a cycloidal spiral. The propagation vector \mathbf{q} is along the direction $[110]$ and the plane of spin-rotation is $(1-10)$.

giving polarizations an order of magnitude lower. Our results clearly demonstrate that the intrinsic polarization of the BiFeO_3 crystals is indeed that expected from calculations.

V. MAGNETIC PROPERTIES

BiFeO_3 presents a G -type antiferromagnetic structure ($T_N=643 \text{ K}$) (Ref. 2) with a long-range cycloidal spiral³ (Fig. 8). The propagation vector \mathbf{q} is along the $[110]$ direction and lies in the plane of spin-rotation $(1-10)$. It is an incommensurate magnetic order with a period length of 62 nm .

We measured magnetization as a function of applied magnetic field and temperature using a superconducting quantum interference device (SQUID quantum device). The magnetization curve obtained at 300 K on the powder sample (Fig. 9) is linear with the field, which is typical for an antiferromagnetic arrangement of the Fe^{3+} magnetic moments, with a slope $\chi=3.59 \times 10^{-3} \text{ emu/mol}$. In the molecular field approximation, the 0 K perpendicular AF susceptibility is given by $\chi_{\perp}=M_0/H_E$, where M_0 is the magnetization of one sublattice and H_E is the first neighbor exchange field.³¹ The latter is linked to the Néel temperature by $k_B T_N=(2/3N)M_0 H_E$ and the powder susceptibility is $\chi_{\text{AF}}=(2/3)\chi_{\perp}$. Using $T_N=643 \text{ K}$, we obtain $\chi_{\text{AF}}=3.40 \times 10^{-3} \text{ emu/mol}$, which is close to the measured slope. Considering this result, the AF susceptibility does not seem to be affected by the cycloidal structure, probably because the period (620 \AA) is very long in comparison with the lattice parameters (about 5 \AA).

The isothermal magnetization curves $M(H)$ of an unleached single crystal (sample S1) of BiFeO_3 at several temperatures, with magnetic field applied perpendicularly to the

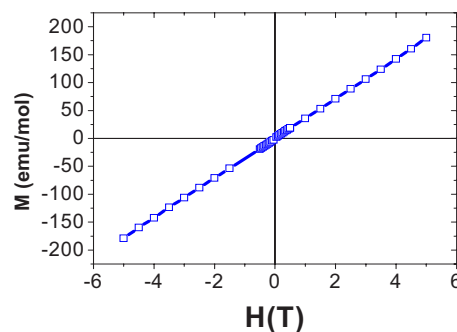


FIG. 9. (Color online) Magnetization curve versus applied magnetic field of the powder sample at room temperature.

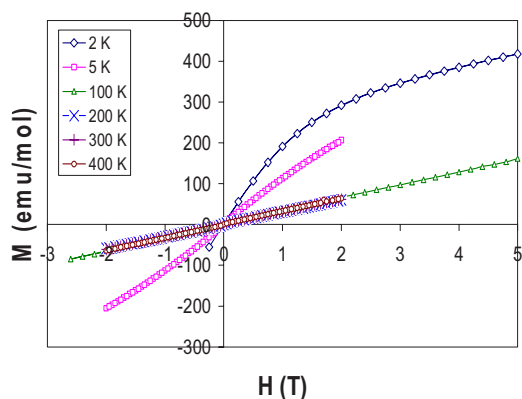


FIG. 10. (Color online) Magnetization curves versus applied magnetic field of an unleached single crystal at several temperatures. The magnetic field is applied perpendicularly to the (012) plane.

(012) plane, are shown in Fig. 10. At 2 and 5 K, we observe an extra contribution, with downwards curvature, superposed on the AF linear field dependence. The magnetization curves versus temperature $M(T)$ under a field of 1 T are shown in Fig. 11, for the unleached crystal S1 and for a crystal leached in diluted HNO_3 (sample S2). One observes a constant magnetization at high temperature, and an upturn below 30 K for sample S1, and below 10 K for sample S2. For sample S1, the nonlinear $M(H)$ observed at 2 and 5 K, and the low temperature upturn of $M(T)$ can be consistently interpreted in terms of, respectively, a Brillouin law and a Curie law due to 1% mol paramagnetic Fe^{3+} ions. It is very likely that these Fe^{3+} ions belong to the $\text{Bi}_{25}\text{FeO}_{39}$ phase formed from the excess of Bi_2O_3 used for the crystal growth. In the unleached sample, this impurity phase amounts thus to 16% of the BiFeO_3 mass. The same analysis made on the $M(T)$ curve of sample S2 shows a strongly reduced impurity content (6% wt). This shows that HNO_3 leaching is efficient in order to remove the $\text{Bi}_{25}\text{FeO}_{39}$ impurity and that the weak ferromagnetism reported in Ref. 27 in polycrystalline BiFeO_3 is in fact due to the presence of a small amount of $\text{Bi}_{25}\text{FeO}_{39}$ impurity. Hence, our measurements confirm that in pure BiFeO_3 weak ferromagnetism vanishes because of the antiferromagnetic cycloidal structure.³²

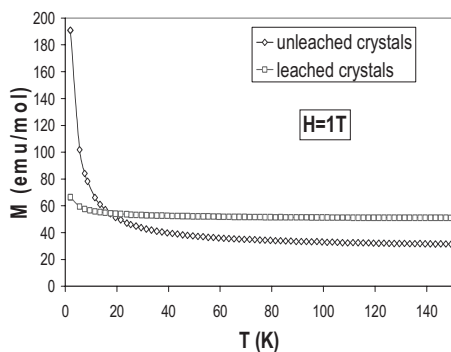


FIG. 11. Magnetization curves versus temperature, under a field of 1 T, of an unleached (\diamond) and of a leached (\square) single crystal of BiFeO_3 . Lines are guides for the eye.

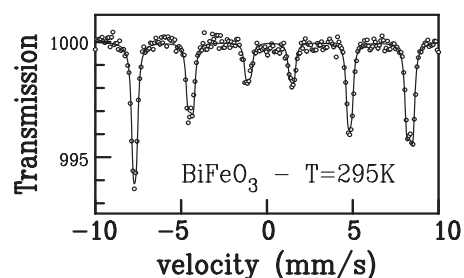


FIG. 12. Room-temperature Mössbauer spectrum of a ceramic sample of BiFeO_3 . The spectral asymmetry is clearly seen on the two outer lines. The line is a fit to an incommensurate spiral structure with a small anisotropy of the hyperfine interaction (see text).

⁵⁷Fe Mössbauer spectroscopy. The first complete study of BiFeO_3 using Mössbauer spectroscopy on ⁵⁷Fe was done by Blaauw and van der Woude.³³ In all the spectra well below T_N , they observe a differential (or inhomogeneous) broadening of the lines, which they tentatively assign to the presence of different nonequivalent Fe sites in the crystal structure. The motivation of our Mössbauer study was to determine whether the observed spectral asymmetry is linked with the spiral magnetic structure, and to examine the relation with the anisotropy observed in the ⁵⁷Fe zero field NMR spectrum of BiFeO_3 .^{14,34} As Bi has a high electronic absorption coefficient for the Mössbauer 14.4 keV γ rays, an absorber was made with Fe 30% enriched in ⁵⁷Fe. The Mössbauer spectrum was recorded using a constant acceleration drive spectrometer and a commercial ⁵⁷Co:Rh γ ray source. For ⁵⁷Fe, 1 mm/s corresponds to 11 MHz.

The spectrum obtained at room temperature, shown in Fig. 12, is very similar to the spectrum at 80 K shown in Ref. 33. It consists of a six-line magnetic hyperfine pattern, with lines somewhat broadened with respect to the minimal experimental linewidth and presenting a sizeable asymmetry, i.e., the spectrum shows inhomogeneous line broadenings. A six-line spectrum is characteristic of magnetically ordered Fe^{3+} moments, and it is due to the presence of a hyperfine magnetic field \mathbf{H}_{hf} acting on the nuclear spin. For Fe^{3+} , \mathbf{H}_{hf} is antiparallel to the magnetic moment \mathbf{m} and its room-temperature value in BiFeO_3 is close to 50 T. A small electric quadrupolar hyperfine interaction \mathcal{H}_Q , due to the coupling of the nuclear quadrupole moment Q of the excited nuclear state (spin $I=3/2$) with the electric field gradient (EFG) at the nucleus site, is also present (the ground nuclear state has spin-1/2, and thus no quadrupole moment). We will show in the following that a spiral magnetic structure leads to line broadenings, due to the small modulation of the excited state hyperfine energies arising when the hyperfine field rotates with respect to the principal axis OZ of the EFG tensor V_{ij} . The total hyperfine Hamiltonian for the excited nuclear state is

$$\mathcal{H}_{\text{hf}} = -g_n \mu_n \mathbf{H}_{\text{hf}} \cdot \mathbf{I} + \mathcal{H}_Q,$$

where g_n is the nuclear gyromagnetic factor and μ_n is the nuclear Bohr magneton. In BiFeO_3 , the point symmetry at the Fe site is trigonal (a threefold axis along the crystal c

axis), and thus the principal axis OZ is the crystal \mathbf{c} axis. Due to the spiral magnetic structure, the Fe moments \mathbf{m} rotate in the hexagonal (1-10) plane containing OZ . For a given orientation Θ of \mathbf{m} (or \mathbf{H}_{hf}) with respect to OZ , one can calculate the hyperfine energies up to second perturbation order of \mathcal{H}_Q with respect to the magnetic interaction for each of the six lines (labeled by the index i). The angle dependent part is

$$\delta^2 E_i(\Theta) = \varepsilon_i 3 \Delta E_Q / 4 (1 + \beta_i \Delta E_Q / h \sin^2 \Theta) \cos^2 \Theta, \quad i = 1 - 6,$$

where the quadrupolar coupling parameter is $\Delta E_Q = eQV_{ZZ}/2$, V_{ZZ} being the principal value of the EFG tensor, $h = 1/2 g_n \mu_n H_{\text{hf}}$, $\varepsilon_i = 1$ for the two outer lines and -1 for the other lines, and β_i is a coefficient which is different for each line. As Θ varies, the variation of $\delta^2 E_i$ gives rise to a spread in hyperfine energy values, i.e., to a line broadening. For the present case of BiFeO_3 of a spiral structure with the principal axis OZ lying in the plane of the moments, and of a very small propagation vector, the angle Θ varies continuously between 0 and 2π ; it is then readily seen that the range of values scanned by $\delta^2 E_i$ is independent of β_i , i.e., it is the same for all the lines, yielding homogeneous broadenings. More generally, it can be shown that a spiral magnetic structure, either commensurate with a small propagation vector or incommensurate, yields homogeneous line broadenings in a ^{57}Fe Mössbauer spectrum when OZ lies in the plane of the magnetic moments; if OZ is perpendicular to this plane, no broadenings occur up to second perturbation order. Inhomogeneous broadenings show up for any other orientation of the principal EFG axis with respect to the plane of the moments. Therefore, the spectral asymmetry observed in BiFeO_3 cannot be accounted for by the presence of the spiral magnetic structure; however, our simulations show that the spiral structure alone accounts for the average line broadening, with a value of the quadrupole coupling parameter $\Delta E_Q = 0.48$ mm/s, very close to the value obtained just above T_N in Ref. 33 (0.44 mm/s).

Recently Zaleski *et al.*^{14,34} made zero field ^{57}Fe NMR measurements in BiFeO_3 below T_N and noted a peculiar shape of the hyperfine spectrum, assigned to an anisotropy of the hyperfine resonance frequency when the hyperfine field rotates in the (1-10) plane. As ^{57}Fe NMR concerns the ground nuclear state with no quadrupole moment, this anisotropy cannot arise from the mechanism discussed above for the Mössbauer spectra. According to Ref. 33, this anisotropy concerns the magnetic hyperfine interaction alone and it is not related to an anisotropy of the Fe^{3+} moment magnitude along the spiral. The angle-dependent NMR frequency is

$$\omega(\Theta) \approx \omega_{\parallel} \cos^2 \Theta + \omega_{\perp} \sin^2 \Theta,$$

and the NMR line shape is well reproduced with an anisotropy parameter $e = \omega_{\parallel} / \omega_{\perp} \approx 0.990$. Following the NMR

study, we introduced an anisotropic variation of the hyperfine field magnitude as the moment rotates in the (1-10) plane,

$$H_{\text{hf}}(\Theta) \approx H_{\parallel} \cos^2 \Theta + H_{\perp} \sin^2 \Theta.$$

Then the spectral asymmetry is very well reproduced with an anisotropy parameter $h = H_{\parallel} / H_{\perp} \approx 0.987$, very close to the NMR value 0.990 (solid line in Fig. 12).

Therefore, the line broadenings and spectral asymmetry of the Mössbauer spectra in the spiral magnetic phase of BiFeO_3 are due to different causes: the broadenings arise from the slight modulation of the hyperfine energies as the magnetic moment rotates with respect to the principal axis of the EFG tensor (crystal \mathbf{c} axis), and the asymmetry stems from an intrinsic anisotropy of the magnetic hyperfine interaction at a site with trigonal symmetry.

VI. CONCLUSION

In summary, we showed that highly pure single crystals of BiFeO_3 can be grown by a flux method. Their high resistivity allows to observe a clear hysteretic polarization loop at room temperature which confirms the ferroelectricity of BiFeO_3 . We infer a large intrinsic electric polarization ($\sim 60 \mu\text{C cm}^{-2}$) like that predicted from the perfect BiFeO_3 unit cell. We conclude that large polarizations are intrinsic to this material and do not stem from some particular property of the thin films. Our magnetic measurements reveal that BiFeO_3 has a pure antiferromagnetic response, without any trace of weak ferromagnetism in contradiction with previous reports on polycrystalline samples. Finally, we show that the slight anisotropy of the magnetic hyperfine interaction introduced for interpreting NMR spectra in BiFeO_3 , perfectly explains the ^{57}Fe Mössbauer spectra. As to magnetoelectric measurements at room temperature, they are yet in progress.

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- ¹W. Eerenstein, N. D. Mathur, and J. F. Scott, *Nature (London)* **442**, 759 (2006).
- ²J. M. Moreau, C. Michel, R. Gerson, and W. J. James, *J. Phys. Chem. Solids* **32**, 1315 (1971).
- ³I. Sosnowska, T. Peterlin-Neumaier, and E. Steichele, *J. Phys. C* **15**, 4835 (1982).
- ⁴R. T. Smith, G. D. Achenbach, R. Gerson, and W. J. James, *J. Appl. Phys.* **39**, 70 (1968).
- ⁵J. Wang, J. B. Neaton, H. Zheng, V. Nagarajan, S. B. Ogale, B. Liu, D. Viehland, V. Vaithyanathan, D. G. Schlom, U. V. Waghmare, N. A. Spaldin, K. M. Rabe, M. Wuttig, and R. Ramesh, *Science* **299**, 1719 (2003).
- ⁶T. Zhao, A. Scholl, F. Zavaliche, K. Lee, M. Barry, A. Doran, M. P. Cruz, Y. H. Chu, C. Ederer, N. A. Spaldin, R. R. Das, D. M. Kim, S. H. Baek, C. B. Eom, and R. Ramesh, *Nat. Mater.* **5**, 823 (2006).
- ⁷H. Béa, S. Fusil, K. Bouzehouane, M. Bibès, M. Sirena, G. Herranz, E. Jacquet, J.-P. Contour, and A. Barthélémy, *Jpn. J. Appl. Phys., Part 2* **45**, L187 (2006).
- ⁸F. Bai, J. Wang, M. Wuttig, J. Li, N. Wang, A. P. Pyatakov, A. K. Zvezdin, L. E. Cross, and D. Viehland, *Appl. Phys. Lett.* **86**, 032511 (2005).
- ⁹W. Eerenstein, F. D. Morrison, J. Dho, M. G. Blamire, J. F. Scott, and N. D. Mathur, *Science* **307**, 1203a (2005).
- ¹⁰W. Eerenstein, F. D. Morrison, J. F. Scott, and N. D. Mathur, *Appl. Phys. Lett.* **87**, 101906 (2005).
- ¹¹V. V. Shvartsman, W. Kleeman, R. Haumont, and J. Kreisel, *Appl. Phys. Lett.* **90**, 172115 (2007).
- ¹²D. Lebeugle, D. Colson, A. Forget, and V. Viret, *Appl. Phys. Lett.* **91**, 022907 (2007).
- ¹³C. Tabares-Munoz, J.-P. Rivera, A. Bezinges, A. Monnier, and H. Schmid, *Jpn. J. Appl. Phys., Suppl.* **24**, 1051 (1985).
- ¹⁴A. V. Zalessky, A. A. Frolov, T. A. Khimich, A. A. Bush, V. S. Pokatilov, and A. K. Zvezdin, *Europhys. Lett.* **50**, 547 (2000).
- ¹⁵E. I. Speranskaya, V. M. Skorikov, and E. Ya. Rode, *Bull. Acad. Sci. USSR, Phys. Ser. (Engl. Transl.)* **30**, 874 (1965).
- ¹⁶S. A. Fedulov, Yu. Venevtsev, G. S. Zhdanov, and E. G. Smazhevskaya, *Kristallografiya* **6**, 795 (1961).
- ¹⁷J. L. Mukherjee and F. F. Y. Wang, *J. Am. Ceram. Soc.* **54**, 32 (1971).
- ¹⁸G. D. Achenbach, W. J. James, and R. Gerson, *J. Am. Ceram. Soc.* **50**, 437 (1967).
- ¹⁹Y. P. Wang, G. L. Yuan, X. Y. Chen, J.-M. Liu, and Z. G. Liu, *J. Phys. D* **39**, 2019 (2006).
- ²⁰A. K. Pradhan, K. Zhang, D. Hunter, J. B. Dadson, G. B. Loutts, P. Bhattacharya, R. Katiyar, J. Zhang, D. J. Sellmer, U. N. Roy, Y. Cui, and A. Burger, *J. Appl. Phys.* **97**, 093903 (2005).
- ²¹H. Béa, M. Bibès, A. Barthélémy, K. Bouzehouane, E. Jacquet, A. Khodan, J.-P. Contour, S. Fusil, A. Forget, D. Lebeugle, D. Colson, and M. Viret, *Appl. Phys. Lett.* **87**, 072508 (2005).
- ²²J.-F. Marucco, P. Gerdanian, and M. Dodé, *J. Chim. Phys. Phys.-Chim. Biol.* **66**, 674 (1974).
- ²³G. M. Sheldrick, *SHELXS-97*, Program for crystal structure solution (University of Göttingen, Göttingen, Germany, 1990).
- ²⁴G. M. Sheldrick, *SHELXL-97*, Program for the refinement of crystal structures from diffraction data (University of Göttingen, Göttingen, Germany, 1997).
- ²⁵L. J. Farrugia, *J. Appl. Crystallogr.* **32**, 837 (1999).
- ²⁶F. Kubel and H. Schmid, *Acta Crystallogr., Sect. B: Struct. Sci.* **46**, 698 (1990).
- ²⁷S. T. Zhang, M. H. Lu, D. Wu, Y. F. Chen, and N. B. Ming, *Appl. Phys. Lett.* **87**, 262907 (2005).
- ²⁸J. B. Neaton, C. Ederer, U. V. Waghmare, N. A. Spaldin, and K. M. Rabe, *Phys. Rev. B* **71**, 014113 (2005).
- ²⁹J. R. Teague, R. Gerson, and W. J. James, *Solid State Commun.* **8**, 1073 (1970).
- ³⁰D. N. Rakov, V. A. Murashov, A. A. Bush, and Yu. N. Venevtsev, *Sov. Phys. Crystallogr.* **33**, 262 (1988).
- ³¹C. Gilles, P. Bonville, H. Rakoto, J. M. Broto, K. K. W. Wong, and S. Mann, *J. Magn. Magn. Mater.* **241**, 430 (2002).
- ³²A. M. Kadomtseva, A. K. Zvezdin, Yu. F. Popov, A. P. Pyatakov, and G. P. Vorob'ev, *JETP Lett.* **79**, 571 (2004).
- ³³C. Blaauw, F. van der Woude, *J. Phys. C* **6**, 1422 (1973).
- ³⁴A. A. Gippius, D. F. Khozeev, E. N. Morozova, A. V. Zalessky, *Phys. Status Solidi A* **196**, 221 (2003).